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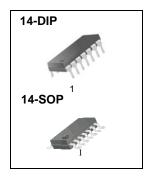
LM319 Dual Comparator

Features

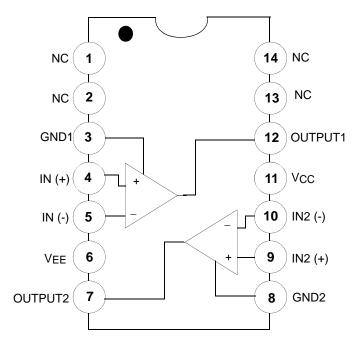
- Operates From a Single 5V Supply
- Typically 80ns Response Time at ± 15 V
- Open Collector Outputs : up to +35V
- High Output Drive Current: 25mA
- Inputs and Outputs can be Isolated From System Ground
- Minimum Fan-Out of 2 (Each Side)
- Two Independent Comparators

Description

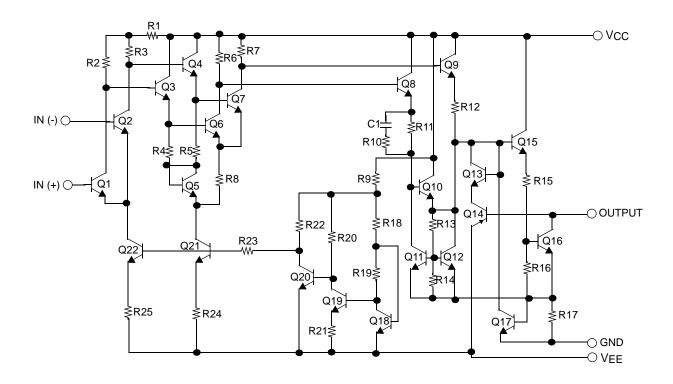
The LM319 is a dual high speed voltage comparator designed to operate from a single +5V supply up to $\pm 15V$ dual supplies. Open collector of the output stage makes the LM319 compatible with RTL, DTL and TTL as well as capable of driving lamps and relays at currents up to 25mA. Typical response time of 80ns with $\pm 15V$ power supplies makes the LM319 ideal for application in fast A/D converts, level shiftier, oscillators, and multivibrators.



Internal Block Diagram



Schematic Diagram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit	
Supply Voltage	Vcc	36	V	
Output to Negative Supply Voltage	Vo - VEE	36	V	
Ground to Negative Supply Voltage	VEE	25	V	
Ground to Positive Supply Voltage	Vcc	18	V	
Differential Input Voltage	VI(DIFF)	5	V	
Input Voltage	Vı	±15	V	
Output Short Circuit Duration	-	10	sec	
Power Dissipation	PD	500	mW	
Thermal Resistance Junction-Ambient Max.	Rθja	250	°C/W	
Operating Temperature Range	TOPR	0 ~ +70	°C	
Storage Temperature Range	TSTG	-65 ~ +150	°C	

Electrical Characteristics

(VCC = +15V, VEE = -15V, $T_A = 25^{\circ}C$, unless otherwise specified)

Parameter	Symbol	Conditions		LM319			Unit
Parameter	Symbol			Min.	Тур.	Max.	Onit
Input Offset Voltage (Note1)	Vio	Rs≤5kΩ		-	2.0	8.0	mV
Input Offset Voltage (Note1)	VIO	VQ = 2V75	Note3	-	-	10	
Input Offset Current (Note1)	lio			-	10	200	nA
input Onset Current (Note I)	lio		Note3	-	-	300	I IIA
Input Pigg Current	Inua			-	150	1000	π Λ
Input Bias Current	IBIAS		Note3	-	-	1200	nA
Voltage Gain	G∨	-		8	40	-	V/mV
Response Time (Note2)	TRES	VCC = ±15V		-	80	-	ns
Saturation Voltage	VSAT	V_{CC} =15 V , V_{EE} = -15 V , V_{I} \leq -5 mV , I_{O} = 25 mA		-	0.6	1.5	
		$V_{CC} = 4.5V, V_{EE} = 0V$ $V_{I} \le -10$ mV, $I_{O} \le 3.2$ mA	Note3	-	0.3	0.4	V
Output Leakage Current	IO(LKG)	\\\ > Fm\\\ \\\\\\\\\\\\\\\\\\\\\\\\\\\\		-	-	-	
		$V_I \ge 5mV$, $V_O(P) = 35V$	Note3	-	-	-	μΑ
		$V_1 \ge 10 \text{mV}, \ V_0(P) = 35 \text{V}$		-	0.2	10]
Input Voltage Range	VI(R)	Note3	VCC = ±15V	-	±13	-	V
			VCC = 5V, VEE = 0V	1	-	3	
Differential Input Voltage	VI(DIFF)	-		-	-	±5	V
Positive Supply Current	ICC1	VCC = 5V, VEE = 0V		-	3.6	-	mΑ
Positive Supply Current	ICC2	VCC = ±15V		-	7.5	12.5	mA
Negative Supply Current	IEE	V _{CC} = ±15V		-	3	5	mA

Notes :

- 1. The offset voltage and offset currents given are the maximum values required to drive the output within a volt of either supply with a 1mA load. Thus, these parameters define an error band and take into account the worst case effects of voltage gain and input impedance.
- 2. The response time specified is for a 100mV input step with 5mV overdrive.
- 3. LM319: $0 \le TA \le +70^{\circ}C$

Typical Performance Characteristics

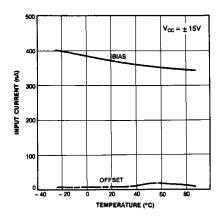


Figure 1. Input Current

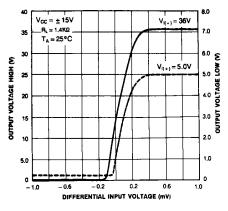


Figure 3. Transfer Function

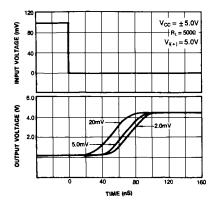


Figure 5. Response Time Various Input Overdriver

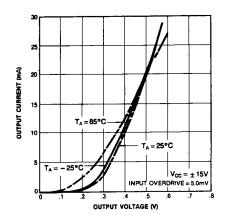


Figure 2. Output Saturation Voltage

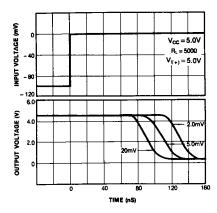


Figure 4. Response Time for Various Input Overdriver

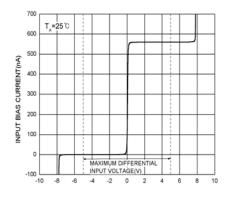


Figure 6. Input Characteristics

Typical Performance Characteristics (Continued)

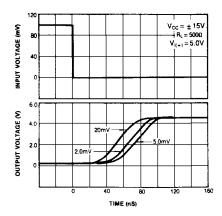


Figure 7. Response Time for Various Input Overdriver

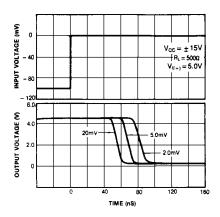


Figure 8. Response Time for Various Input Overdriver

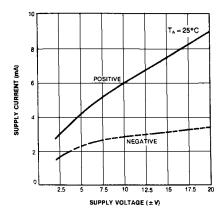


Figure 9. Supply Current

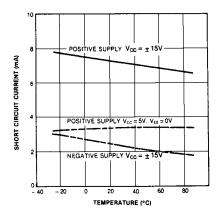


Figure 10. Supply Current

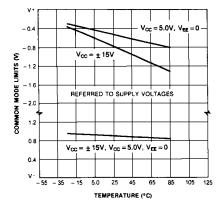


Figure 11. Common Mode Limits

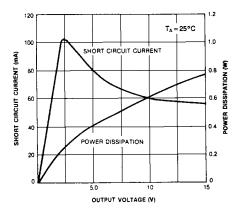
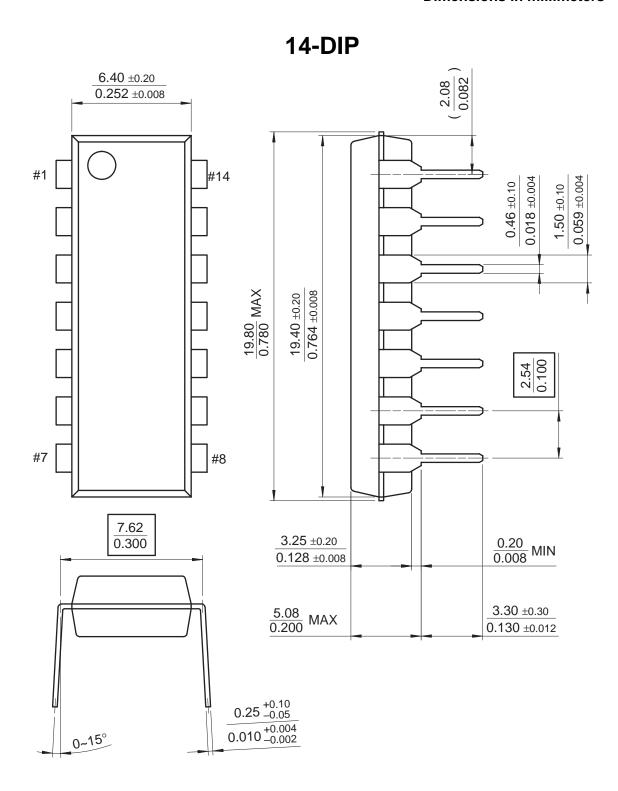


Figure 12. Output Limiting Characteristics

Mechanical Dimensions

Package

Dimensions in millimeters



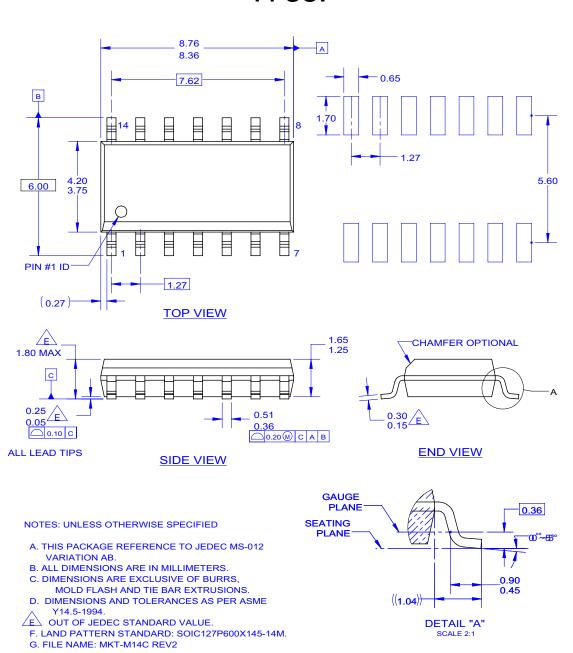
Mechanical Dimensions (Continued)

Package

Dimensions in millimeters

SCALE 2:1

14-SOP



Ordering Information

Product Number	Package	Operating Temperature
LM319N	14-DIP	0 ~ +70°C
LM319M	14-SOP	0~+70 C

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